

EPO-TEK® H70E-2

Technical Data Sheet For Reference Only

Thermally Conductive, Electrically Insulating Epoxy

Date: November 2019

Rev: VIII
No. of Components: Two
Mix Ratio by Weight: 1:1

Specific Gravity: Part A: 1.50 Part B: 2.30

Pot Life: 2 Days

Shelf Life- Bulk: One year at room temperature

Recommended Cure: 150°C / 1 Hour

Minimum Alternative Cure(s):

May not achieve performance properties listed below

175°C / 1 Minute 150°C / 5 Minutes 120°C / 15 Minutes 80°C / 90 Minutes

NOTES:

• Container(s) should be kept closed when not in use.

• Filled systems should be stirred thoroughly before mixing and prior to use.

• Performance properties (rheology, conductivity, others) of the product may vary from those stated on the data sheet when bi-pak/syringe packaging or post-processing of any kind is performed. Epoxy's warranties shall not apply to any products that have been reprocessed or repackaged from Epoxy's delivered status/container into any other containers of any kind, including but not limited to syringes, bi-paks, cartridges, pouches, tubes, capsules, films or other packages.

<u>Product Description:</u> EPO TEK® H70E-2 is a two component, thermally conductive electrically insulating epoxy designed for glob-top chip protection in TAB and COB die-attach technologies. It is used to prevent chips from being mechanically damaged during micropackage assembly and handling.

<u>Typical Properties:</u> Cure condition: 150°C / 1 Hour Different batches, conditions & applications yield differing results.

Data below is not guaranteed. To be used as a guide only, not as a specification. * denotes test on lot acceptance basis

PHYSICAL PROPERTIES:						
* Color (before cure):	Part A: Black Par				Cream	
* Consistency:	Smooth thixotropic p			paste		
* Viscosity (23°C) @ 20 rpm:		9,0	000 - 15,000	cPs		
Thixotropic Index:			1.7			
* Glass Transition Temp:			≥ 80	°C (D)	/namic Cure: 20-200°C/ISO 25 Min; Ramp -10-200°C @20°C/Min)	
Coefficient of Thermal Expansi	ion (CTE):					
	Below Tg:		20	х 10 ⁻⁶	in/in°C	
	Above Tg:		112	х 10 ⁻⁶	in/in°C	
Shore D Hardness:			65			
Lap Shear @ 23°C:			> 2,000	psi		
Die Shear @ 23°C:			≥ 5	Kg	1,778 psi	
Degradation Temp:			447	°C		
Weight Loss:						
	@ 200°C:		0.10	%		
	@ 250°C:		0.30	%		
	@ 300°C:		0.70	%		
Suggested Operating Temperature:			< 300	°C (Ir	°C (Intermittent)	
Storage Modulus:			1,214,415	psi		
Ion Content:		Cl⁻:	267 ppm			
* Particle Size:			≤ 50	micro	ns	

ELECTRICAL AND THERMAL PROPERTIES:		
Thermal Conductivity:	1.0	W/mK
Volume Resistivity @ 23°C:	$\geq 8 \times 10^{12}$	Ohm-cm
Dielectric Constant (1KHz):	5.19	
Dissipation Factor (1KHz):	0.007	



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EPO-TEK® H70E-2 Advantages & Suggested Application Notes:

- The epoxy exhibits resistance against moisture, contamination and solvents which make it an ideal glob top. See Technical Paper #24 in our library for process flow in TAB packaging and reliability study http://www.epotek.com/technical-papers.asp.
- A slightly thixotropic paste with excellent handling characteristics, pot life and short curing cycles. The rheology provides a dot-shape or dome configuration over wire-bonded die. Capable of glob-top DAM-and-FILL, or single-dot glob-top.
- Suitable for mass production as semiconductor encapsulant; low temp cure 80°C capable, controlled viscosity. Capable of many packages including TAB, COB, CSPs, BGAs, DIP and TO-cans.
- Excellent adhesion to PCB, ferrous and non-ferrous metals, glass, ceramic, epoxy package shells and semiconductor materials.
- Recommended for chip bonding, circuit repair, reinforce lead-frames, LSI chip packaging and good heat dissipation.